

NSVBC114EPDXV6T1G

NSVBC114EPDXV6T1G Information



For Reference Only

Part Number	NSVBC114EPDXV6T1G	
Manufacturer	ON Semiconductor	
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays, Pre-Biased	
Description	TRANS NPN/PNP BIAS SOT563	
Package	SOT-563, SOT-666	
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com	



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



NSVBC114EPDXV6T1G Specifications

	Report errors?
Supplier Device Package	SOT-563
Package / Case	SOT-563, SOT-666
Mounting Type	Surface Mount
Power - Max	500mW
Frequency - Transition	-
Current - Collector Cutoff (Max)	500nA
Vce Saturation (Max) @ Ib, Ic	250mV @ 300µA, 10mA
DC Current Gain (hFE) (Min) @ Ic, Vce	35 @ 5mA, 10V
Resistor - Emitter Base (R2) (Ohms)	10k
Resistor - Base (R1) (Ohms)	10k
Voltage - Collector Emitter Breakdown (Max)	50V
Current - Collector (Ic) (Max)	100mA
Transistor Type	1 NPN, 1 PNP - Pre-Biased (Dual)
Series	-
Package	SOT-563, SOT-666
	Transistors - Bipolar (BJT) - Arrays, Pre-Biased
Category	Discrete Semiconductor Products
Manufacturer	ON Semiconductor
Manufacturer Part Number	NSVBC114EPDXV6T1G

NSVBC114EPDXV6T1G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

NSVBC114EPDXV6T1G Payment Methods



If you have any question about NSVBC114EPDXV6T1G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com